



Features

- RoHS compliant*
- Glass passivated chip
- Low reverse leakage current
- Low forward voltage drop
- High current capability

CD214A-R150~R12000 Glass Passivated Rectifiers

General Information

The markets of portable communications, computing and video equipment are challenging the semiconductor industry to develop increasingly smaller electronic components. Bourns offers Glass Passivated Rectifiers for rectification applications, in compact chip DO-214AC (SMA) size format, which offer PCB real estate savings and are considerably smaller than most competitive parts. The Glass Passivated Rectifier Diodes offer a forward current of 1 A with a choice of repetitive peak reverse voltage of 50 V up to 2000 V.

Bourns® Chip Diodes conform to JEDEC standards, are easy to handle on standard pick and place equipment and their flat configuration minimizes roll away.

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	CD214A-					Unit
		R150	R1100	R1200	R1400	R1600	
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	V
Max. Average Forward Rectified Current ¹	$I_{(AV)}$	1.0					A
DC Reverse Current @ Rated DC Blocking Voltage (@ $T_J = 25^\circ\text{C}$)	I_R	5.0					μA
DC Reverse Current @ Rated DC Blocking Voltage (@ $T_J = 125^\circ\text{C}$)	I_R	30					μA
DC Reverse Current @ Rated DC Blocking Voltage (@ $T_J = 150^\circ\text{C}$)	I_R	50					μA
Typical Junction Capacitance ²	C_J	12					pF
Maximum Instantaneous Forward Voltage @ 1 A	V_F	1.0					V
Typical Thermal Resistance ³	$R_{\theta JA}$ $R_{\theta JL}$	75 27					$^\circ\text{C/W}$ $^\circ\text{C/W}$
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30					A

Notes:

1 See Forward Derating Curve.

2 Measured @ 1.0 MHz and applied reverse voltage of 4.0 VDC.

3 Thermal resistance from junction to ambient and from junction to lead P.C.B. mounted on 0.2 ~ x 0.2 ~ (5.0 mm x 5.0 mm) copper pad areas.

*RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011.

Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

CD214A-R150~R12000 Glass Passivated Rectifiers

BOURNS®

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	CD214A-						Unit
		R1800	R11000	R11100	R11200	R11600	R12000	
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	800	1000	1100	1200	1600	2000	V
Maximum RMS Voltage	V _{RMS}	560	700	770	840	1120	1400	V
Maximum DC Blocking Voltage	V _{DC}	800	1000	1100	1200	1600	2000	V
Max. Average Forward Rectified Current ¹	I _(AV)	1.0						A
DC Reverse Current @ Rated DC Blocking Voltage (@T _J = 25 °C)	I _R	5.0						μA
DC Reverse Current @ Rated DC Blocking Voltage (@T _J = 125 °C)	I _R	30		50				μA
Typ. Junction Capacitance ²	C _J	12						pF
Maximum Instantaneous Forward Voltage @ 1 A	V _F	1.0		1.25			2.0	V
Typical Thermal Resistance ³	R _{θJA}	75						°C/W °C/W
	R _{θJL}	27						
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30		25			25	A

Notes:

1 See Forward Derating Curve.

2 Measured @ 1.0 MHz and applied reverse voltage of 4.0 VDC.

3 Thermal resistance from junction to ambient and from junction to lead P.C.B. mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas.

Thermal Characteristics (@ $T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	CD214A-R150~R12000	Unit
Operating Temperature Range	T_J	-65 to +175	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +175	$^\circ\text{C}$

Specifications are subject to change without notice.

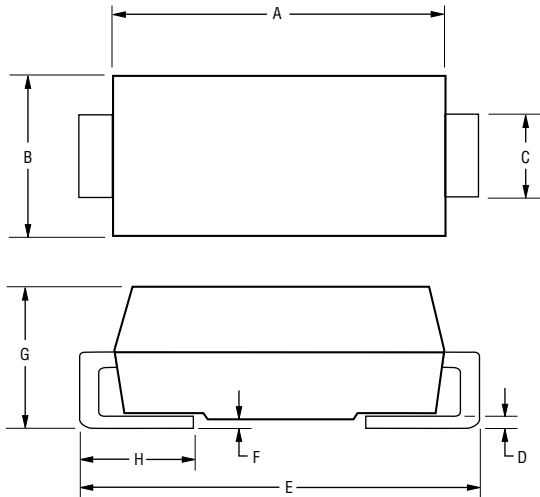
The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

CD214A-R150~R12000 Glass Passivated Rectifiers

BOURNS®

Product Dimensions

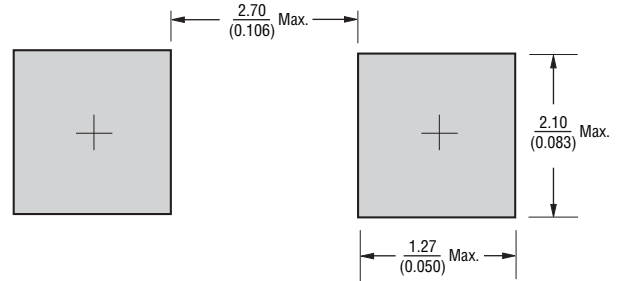
This is an RoHS compliant molded plastic package. The polarity is indicated by a cathode band and weighs approximately 0.064 g. The package and dimensions are shown below.



DIMENSIONS: $\frac{\text{MM}}{(\text{INCHES})}$

Dimensions	DO-214AC (SMA)
A	$\frac{4.06 - 4.57}{(0.160 - 0.180)}$
B	$\frac{2.29 - 2.92}{(0.090 - 0.115)}$
C	$\frac{1.27 - 1.63}{(0.050 - 0.064)}$
D	$\frac{0.15 - 0.31}{(0.006 - 0.112)}$
E	$\frac{4.83 - 5.59}{(0.190 - 0.220)}$
F	$\frac{0.05 - 0.20}{(0.002 - 0.008)}$
G	$\frac{2.01 - 2.62}{(0.080 - 0.103)}$
H	$\frac{0.76 - 1.52}{(0.030 - 0.060)}$

Recommended Pad Layout



DIMENSIONS: $\frac{\text{MM}}{(\text{INCHES})}$

Physical Specifications

CaseMolded plastic per UL Class 94V-0
 PolarityBand indicates diode cathode
 Weight0.002 ounces / 0.064 grams

How To Order

CD 214A - R 1 50

Common Code
 Chip Diode
 Package
 • 214A = SMA/DO-214AC
 Model
 R = Glass Passivated Rectifiers
 Forward Current $I_{(AV)}$
 1 = 1 A
 Reverse Voltage
 50 = 50 V 1000 = 1000 V
 100 = 100 V 1100 = 1100 V
 200 = 200 V 1200 = 1200 V
 400 = 400 V 1600 = 1600 V
 600 = 600 V 2000 = 2000 V
 800 = 800 V

Typical Part Marking

CD214A-R150 **B** R1A
 CD214A-R1100 **B** R1B
 CD214A-R1200 **B** R1D
 CD214A-R1400 **B** R1G
 CD214A-R1600 **B** R1J
 CD214A-R1800 **B** R1K
 CD214A-R11000 **B** R1M
 CD214A-R11100 **B** R1N
 CD214A-R11200 **B** R1Q
 CD214A-R11600 **B** R1Y
 CD214A-R12000 **B** R1Z

Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.

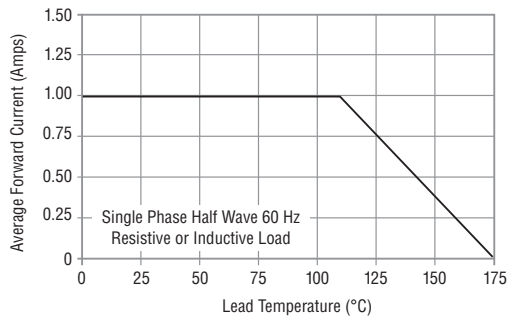
Users should verify actual device performance in their specific applications.

CD214A-R150~R12000 Glass Passivated Rectifiers

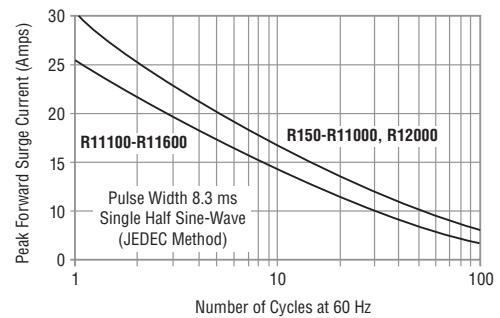
BOURNS®

Rating and Characteristic Curves

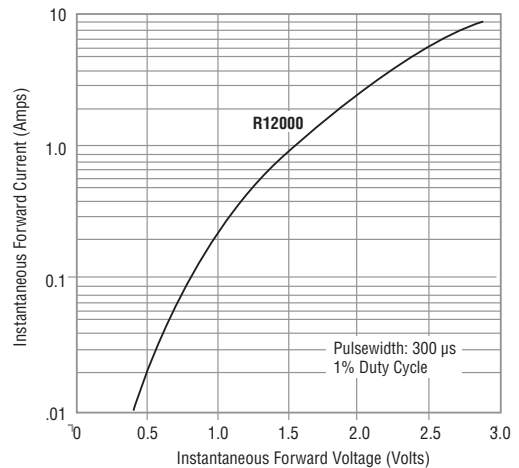
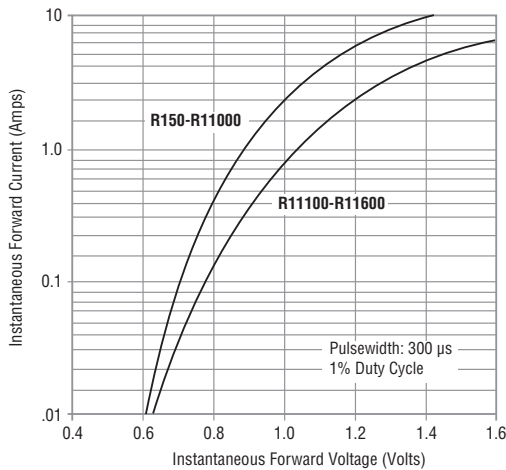
Forward Current Derating Curve



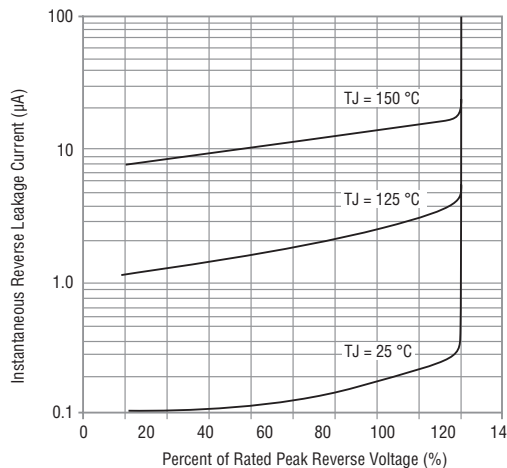
Non-Repetitive Surge Current



Forward Characteristics



Reverse Characteristics



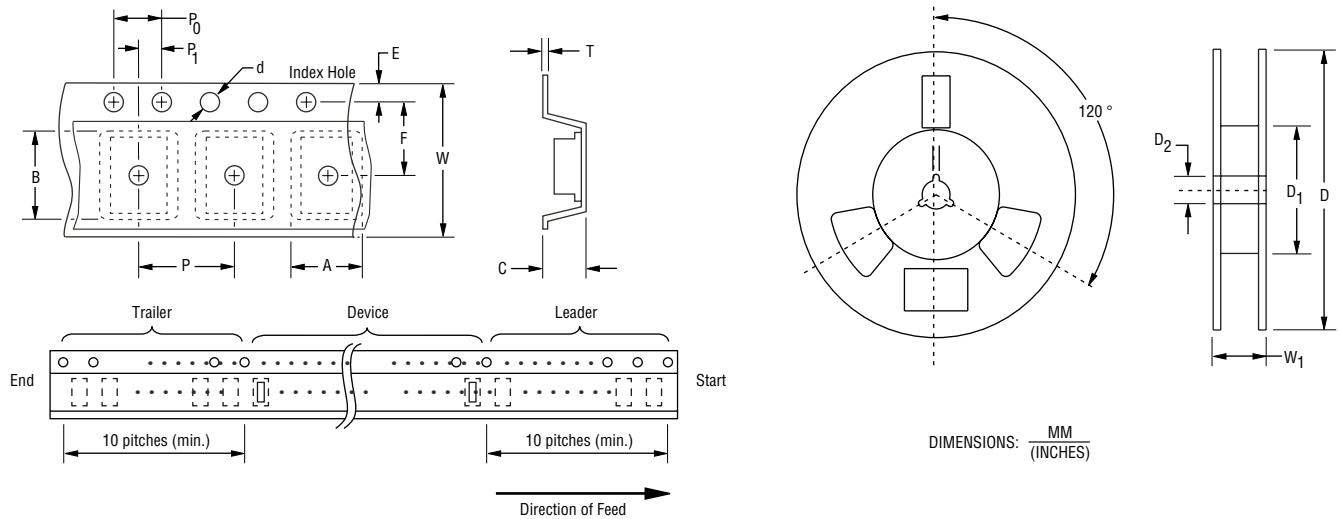
Specifications are subject to change without notice. The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

CD214A-R150~R12000 Glass Passivated Rectifiers

BOURNS®

Packaging Information

The surface mount product is packaged in a 12 mm x 4 mm tape and reel format per EIA-481 standard.



Item	Symbol	DO-214AC (SMA)
Carrier Width	A	$\frac{3.42 \pm 0.10}{(0.134 \pm 0.004)}$
Carrier Length	B	$\frac{5.07 \pm 0.10}{(0.199 \pm 0.004)}$
Carrier Depth	C	$\frac{3.10 \pm 0.10}{(0.122 \pm 0.004)}$
Sprocket Hole	d	$\frac{1.55 \pm 0.05}{(0.061 \pm 0.002)}$
Reel Outside Diameter	D	$\frac{330}{(12.992)}$
Reel Inner Diameter	D ₁	$\frac{50.0}{(1.969)} \text{ Min.}$
Feed Hole Diameter	D ₂	$\frac{13.0 \pm 0.50}{(0.512 \pm 0.020)}$
Sprocket Hole Position	E	$\frac{1.75 \pm 0.10}{(0.069 \pm 0.004)}$
Punch Hole Position	F	$\frac{5.50 \pm 0.50}{(0.217 \pm 0.020)}$
Punch Hole Pitch	P	$\frac{4.00 \pm 0.10}{(0.157 \pm 0.004)}$
Sprocket Hole Pitch	P ₀	$\frac{4.00 \pm 0.10}{(0.157 \pm 0.004)}$
Embossment Center	P ₁	$\frac{2.00 \pm 0.05}{(0.079 \pm 0.002)}$
Overall Tape Thickness	T	$\frac{0.30 \pm 0.10}{(0.012 \pm 0.004)}$
Tape Width	W	$\frac{12.00 \pm 0.20}{(0.420 \pm 0.008)}$
Reel Width	W ₁	$\frac{18.7}{(0.736)} \text{ Max.}$
Quantity per Reel	—	7,500

REV. 04/15
 Specifications are subject to change without notice.
 The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9